



# **Small Signal Schottky Diode**



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## **MECHANICAL DATA**

Case: MiniMELF (SOD-80)

Weight: approx. 31 mg

Cathode band color: black

#### Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

# **FEATURES**

- For general purpose applications
- This diode features low turn-on voltage. The devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges



- Metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring
- · The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications
- This diode is also available in a DO-35 case with type designation BAT86
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## **APPLICATIONS**

· Applications where a very low forward voltage is required

PARTS TABLE			
PART	ORDERING CODE	CIRCUIT CONFIGURATION	REMARKS
BAS86	BAS86-GS18 or BAS86-GS08	Single	Tape and reel

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Continuous reserve voltage		V <sub>R</sub>	50	V	
Forward continuous current <sup>(1)</sup>		IF	200	mA	
Repetitive peak forward current (1)	$t_p$ < 1 s, $\delta \le 0.5$	I <sub>FRM</sub>	500	mA	
Power dissipation <sup>(1)</sup>		P <sub>tot</sub>	200	mW	

#### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature

<b>THERMAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air <sup>(1)</sup>		R <sub>thJA</sub>	300	K/W	
Junction temperature		Tj	125	°C	
Ambient operating temperature range		T <sub>amb</sub>	-65 to +125	°C	
Storage temperature range		T <sub>stg</sub>	-65 to +150	°C	

#### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature

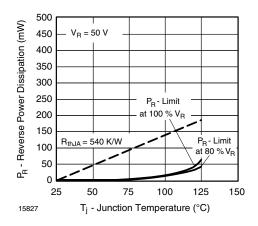
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# **Vishay Semiconductors**

**BAS86** 

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Reserve breakdown voltage	$I_R = 10 \ \mu A$ (pulsed)	V <sub>(BR)</sub>	50			V
Leakage current	V <sub>R</sub> = 40 V	I <sub>R</sub>			5	μA
	Pulse test t <sub>p</sub> < 300 $\mu$ s, I <sub>F</sub> = 0.1 mA, $\delta$ < 2 %	V <sub>F</sub>		200	300	mV
	Pulse test t <sub>p</sub> < 300 $\mu$ s, I <sub>F</sub> = 1 mA, $\delta$ < 2 %	V <sub>F</sub>		275	380	mV
Forward voltage	Pulse test t <sub>p</sub> < 300 $\mu$ s, I <sub>F</sub> = 10 mA, $\delta$ < 2 %	V <sub>F</sub>		365	450	mV
	Pulse test t <sub>p</sub> < 300 $\mu$ s, l <sub>F</sub> = 30 mA, $\delta$ < 2 %	V <sub>F</sub>		460	600	mV
	Pulse test t <sub>p</sub> < 300 $\mu$ s, I <sub>F</sub> = 100 mA, $\delta$ < 2 %	V <sub>F</sub>		700	900	mV
Diode capacitance	V <sub>R</sub> = 1 V, f = 1 MHz	CD			8	pF
Reserve recovery time	$I_F = 10 \text{ mA}, I_R = 10 \text{ mA},$ $i_R = 1 \text{ mA}$	t <sub>rr</sub>			5	ns

#### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)





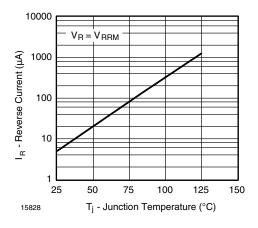


Fig. 2 - Reverse Current vs. Junction Temperature

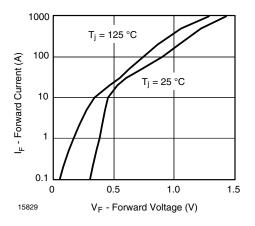


Fig. 3 - Forward Current vs. Forward Voltage

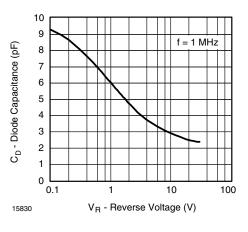


Fig. 4 - Diode Capacitance vs. Reverse Voltage

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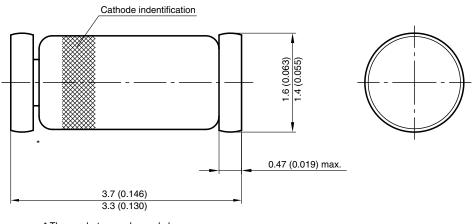
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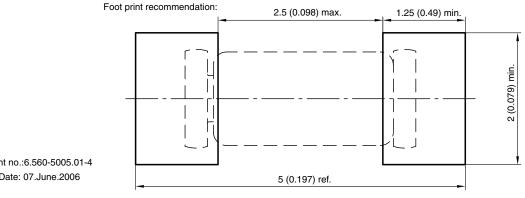


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#### PACKAGE DIMENSIONS in millimeters (inches): MiniMELF SOD-80



<sup>\*</sup> The gap between plug and glass can be either on cathode or anode side



Document no.:6.560-5005.01-4 Rev. 8 - Date: 07.June.2006 96 12070



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